



# STDD15 series

## LOW CAPACITANCE DETECTION DIODE

### MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	10 mA
$V_{RRM}$	15 V
$T_j(\text{max})$	150 °C
$V_F(\text{max})$	0.51 V

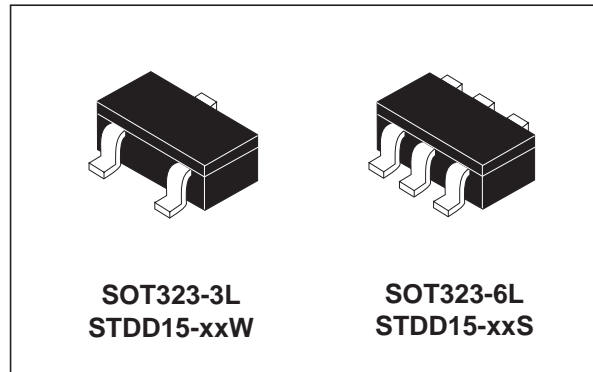
### FEATURES AND BENEFITS

- Low diode capacitance
- Device designed for RF application
- Low profile package
- Available in 3 configurations
- Very low parasitic inductor & resistor

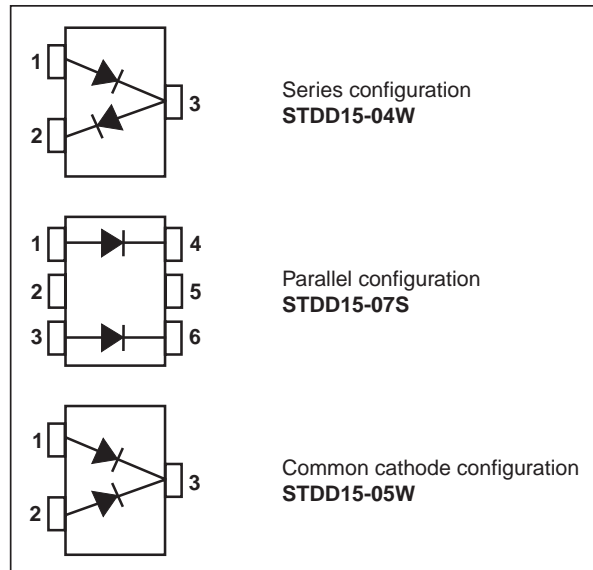
### DESCRIPTION

The STDD15 is a dual diode series for the detection of a RF signal and the compensation of the voltage drift with the temperature. The SOT323 package makes the device ideal in application where the space saving is critical like mobile phones.

The low junction capacitance will reduce the disturbance on the RF signal



### SCHEMATIC DIAGRAM



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	15	V
$I_F$	Continuous forward current	10	mA
$I_{FSM}$	Surge non repetitive forward current	2	A
	$t_p = 10\text{ms}$		
$T_{stg}$	Storage temperature range	- 65 + 150	°C
$T_j$	Maximum operating junction temperature	150	°C

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### THERMAL PARAMETERS

Symbol	Parameter	Value	Unit
$R_{th(j-a)}^*$	Junction to ambient	500	°C/W

\*: Mounted with minimum recommended pad size, PC board FR4.

### STATIC ELECTRICAL CHARACTERISTICS

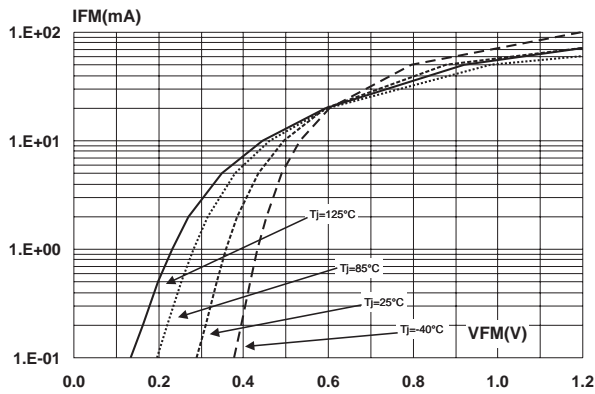
Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
$I_R^*$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = 1\text{V}$			0.035	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$			6	30	
		$T_j = 25^\circ\text{C}$	$V_R = 15\text{V}$			0.23	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$			10	100	
$V_F^*$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 1\text{mA}$		350	380	mV
		$T_j = 125^\circ\text{C}$			230	260	
		$T_j = 25^\circ\text{C}$	$I_F = 10\text{mA}$		500	570	
		$T_j = 125^\circ\text{C}$			450	510	

\* Pulse test:  $t_p \leq 250\mu\text{s}$ ,  $\Delta \leq 2\%$

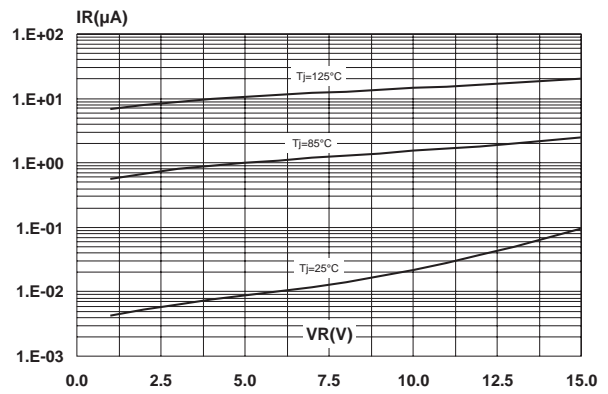
### ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
C	Diode capacitance	$V_R = 0\text{V}$	$F = 1\text{MHz}$			1.0	pF
$R_F$	Forward resistance	$I_F = 5\text{mA}$	$F = 100\text{MHz}$		15		$\Omega$
Ls	Series inductance				1.5		nH

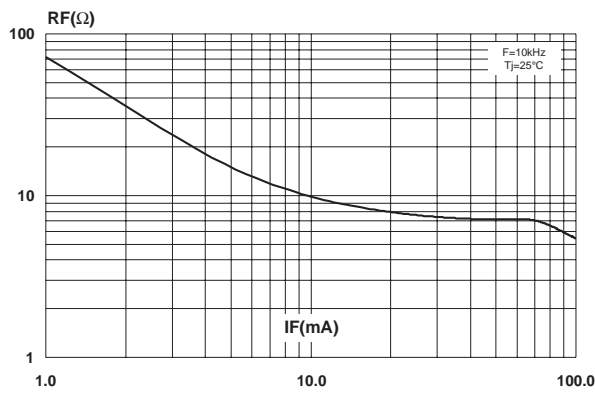
**Fig. 1:** Forward voltage drop versus forward current (typical values).



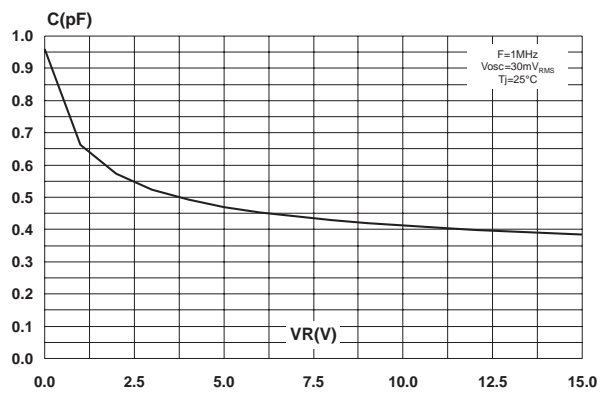
**Fig. 2:** Reverse leakage current versus reverse voltage applied (typical values).



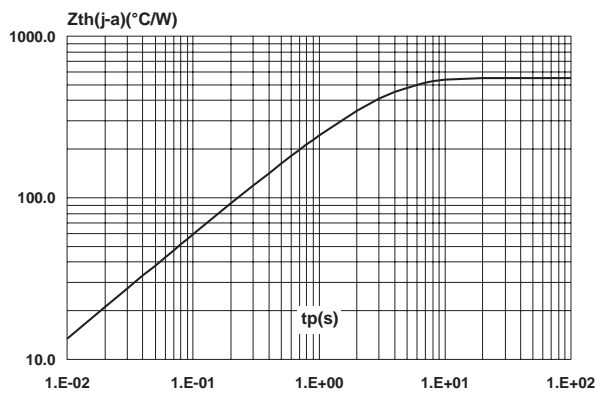
**Fig. 3:** Differential forward resistance versus forward current (typical values).



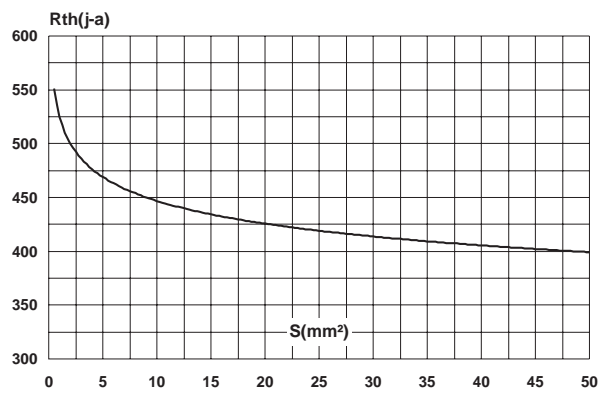
**Fig. 4:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 5:** Variation of thermal impedance junction to ambient versus pulse duration (printed circuit board, epoxy FR4).



**Fig. 6:** Thermal resistance junction to ambient versus copper surface under each lead (printed circuit board, epoxy FR4)..



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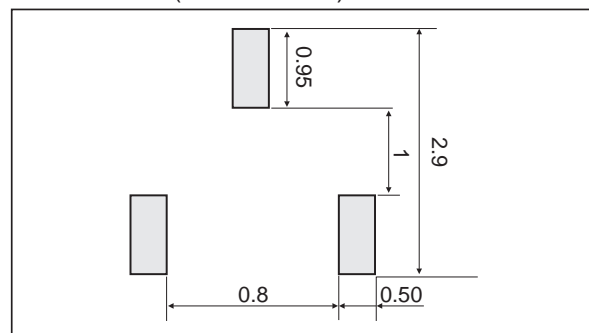
### Electrical Model (PSPICE)

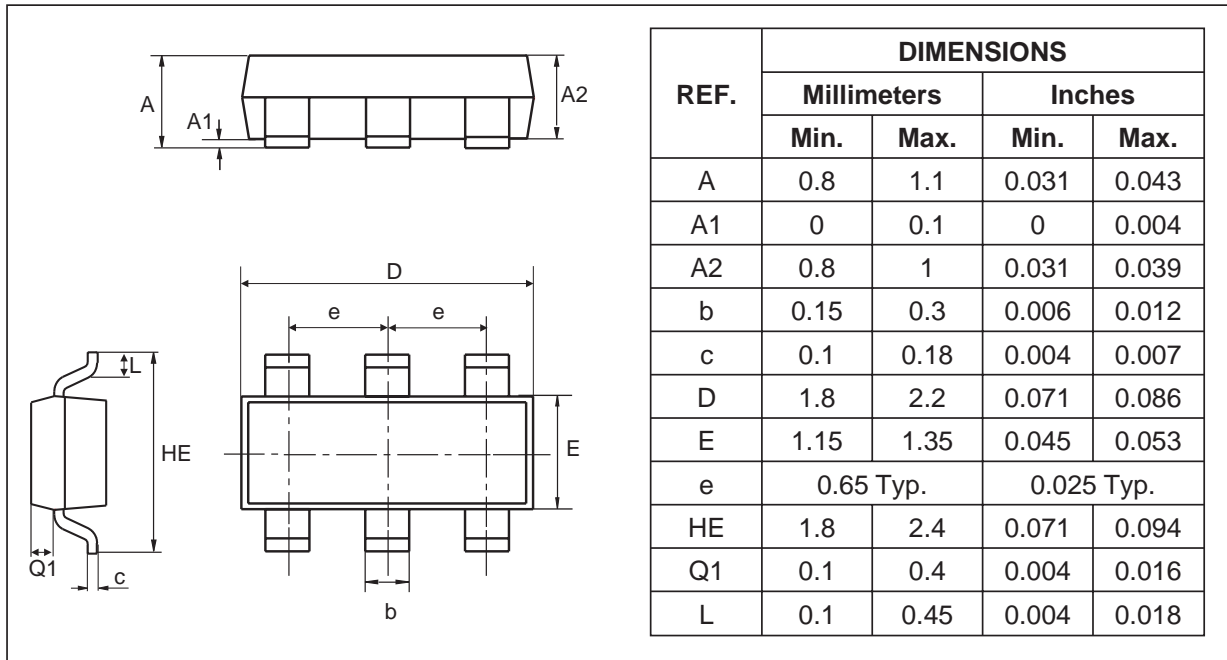
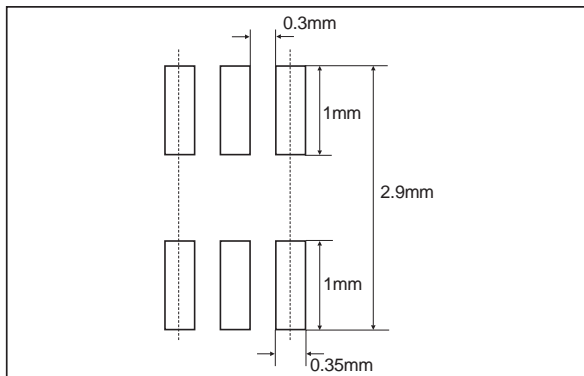
Parameter	Value	Unit
Is	2.66 e-8	A
N	1.04	
M	0.772	
Vj	0.65	V
Eg	0.69	eV
Xti	2	
Rs	15	W
Cjo	0.85 e-12	F
Bv	20	V
Ibv	10 e-3	A

### PACKAGE MECHANICAL DATA SOT323-3L

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.8		1.1	0.031		0.043
A1	0.0		0.1	0.0		0.004
b	0.25		0.4	0.010		0.016
c	0.1		0.26	0.004		0.010
D	1.8	2.0	2.2	0.071	0.079	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
e		0.65			0.026	
H	1.8	2.1	2.4	0.071	0.083	0.094
L	0.1	0.2	0.3	0.004	0.008	0.012
$\theta$	0		30°	0		30°

### FOOTPRINT (in millimeters)



**PACKAGE MECHANICAL DATA**  
 SOT323-6L

**FOOTPRINT (in millimeters)**


**Note:** The device fulfills the MSL level 1 after leadfree soldering profile.

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STDD15-04W	24	SOT323-3L	0.006 g	3000	Tape & reel
STDD15-05W	25	SOT323-3L	0.006 g	3000	Tape & reel
STDD15-07S	D25	SOT323-6L	0.006 g	3000	Tape & reel

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